



isc Silicon PNP Power Transistor

DESCRIPTION

- · Collector-Emitter BreakdownVoltage-
- : V_{(BR)CEO}= -50V(Min.)
- · Low Collector Saturation Voltage-
- : V_{CE(sat)}= -1.2(Max.) @I_C= -3A
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

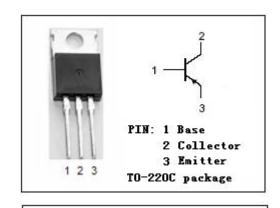


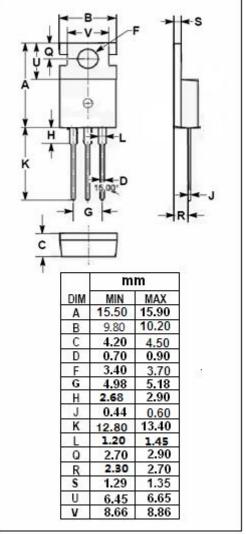
APPLICATIONS

• Designed for use in general purpose amplifier and switching applications.



| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|-------|------------|
| V _{CBO} | Collector-Base Voltage | -50 | V |
| V _{CEO} | Collector-Emitter Voltage | -50 | V |
| V _{EBO} | Emitter-Base Voltage | -6 | V |
| Ic | Collector Current-Continuous | -3 | Α |
| I _{CM} | Collector Current-Peak | -5 | А |
| Pc | Collector Power Dissipation@T _C =25°C | 25 | W |
| TJ | Junction Temperature | 150 | |
| T _{stg} | Storage Temperature -55~150 | | $^{\circ}$ |







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2SB898

ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|----------------------|--------------------------------------|---|-----|------|------|------|
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | I _C = -10mA; R _{BE} = ∞ | -50 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = -1mA; I _C = 0 | -6 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = -3A; I _B = -0.375A | | | -1.2 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = -3A; V _{CE} = -4V | | | -1.8 | V |
| Ісво | Collector Cutoff Current | V _{CB} = -50V; I _E = 0 | | | -100 | μА |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = -6V; I _C = 0 | | | -10 | μА |
| h _{FE-1} | DC Current Gain | I _C = -1A; V _{CE} = -4V | 50 | | 200 | |
| h _{FE-2} | DC Current Gain | I _C = -3A; V _{CE} = -4V | 10 | | | |
| f⊤ | Current-Gain—Bandwidth Product | I _C = -0.5A ; V _{CE} = -10V | 5 | | | MHz |

Notice:

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